

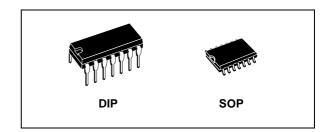


QUAD EXCLUSIVE OR GATE

- MEDIUM-SPEED OPERATION $t_{PHL} = t_{PLH} = 70 \text{ns}$ (Typ.) at CL = 50 pF and $V_{DD} = 10 \text{V}$
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I_I = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT



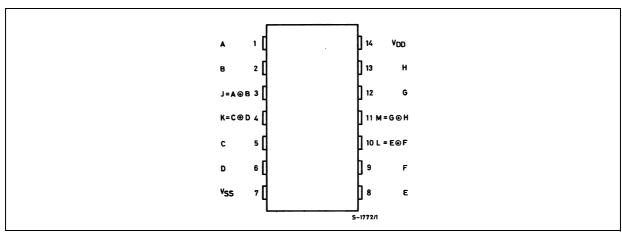
The HCF4070B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4070B contain four independent exclusive OR gates. This device provide the system designer with a means for direct implementation of the exclusive-OR. For applications as logical comparators, adders/subtractors, parity generator and checkers.



ORDER CODES

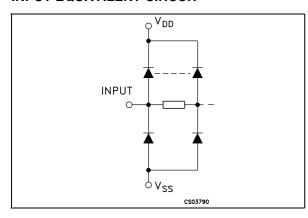
PACKAGE	TUBE	T&R
DIP	HCF4070BEY	
SOP	HCF4070BM1	HCF4070M013TR

PIN CONNECTION

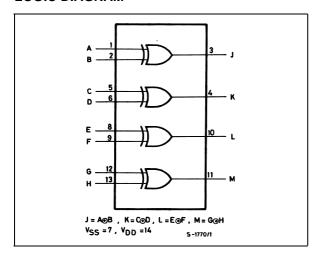


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INPUT EQUIVALENT CIRCUIT



LOGIC DIAGRAM



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
1, 5, 8, 12	A, C, E, G	Data Inputs
2, 6, 9, 13	B, D, F, H	Data inputs
3, 4, 10, 11	J, K, L, M	Data Outputs
7	V_{SS}	Negative Supply Voltage
14	V_{DD}	Positive Supply Voltage

TRUTH TABLE

INP	UTS	OUTPUT
A, C, E, G	B, D, F, H	J, K, L, M
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

DC SPECIFICATIONS

		Test Condition			Value								
Symbol	Parameter	Vı	$v_1 v_0$	llol '	V _{DD}	T _A = 25°C		-40 to 85°C		-55 to 125°C		Unit	
		(V)	(V)	(μA)	(μ A) (V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.02	1		30		30	
		0/10			10		0.02	2		60		60	۸
	0/15			15		0.02	4		120		120	μΑ	
		0/20			20		0.04	20		600		600	
V _{OH}	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
V _{OL}	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
V_{IH}	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		
	Voltage		1/9	<1	10	7			7		7		V
			1.5/13.5	<1	15	11			11		11		
V_{IL}	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I _{OH}	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.15		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		ША
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
I_{OL}	Output Sink	0/5	0.4	<1	5	0.44	1		0.36		0.36		
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mA
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
IJ	Input Leakage Current	0/18	Any In	put	18		±10 ⁻⁵	±0.1		±1		±1	μΑ
C _I	Input Capacitance		Any In	put			5	7.5					pF

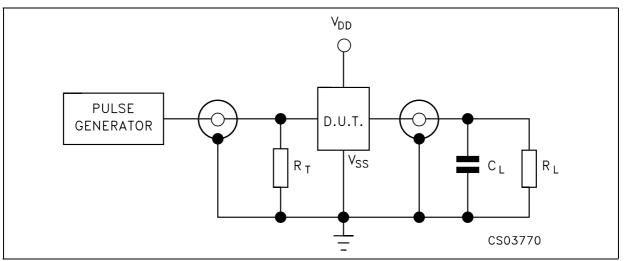
The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \ (T_{amb} = 25 ^{\circ}C, \ C_{L} = 50 pF, \ R_{L} = 200 K\Omega, \ t_{f} = t_{f} = 20 \ ns)$

Complete	Donomotor	Test Condition			Value (*)		
Symbol	Parameter	V _{DD} (V)		Min.	Тур.	Max.	
t _{PLH} t _{PHL}	Propagation Delay Time	5			140	280	
		10			70	130	ns
		15			50	100	
t _{TLH} t _{THL}	Output Transition Time	5			100	200	
		10			50	100	ns
		15			40	80	

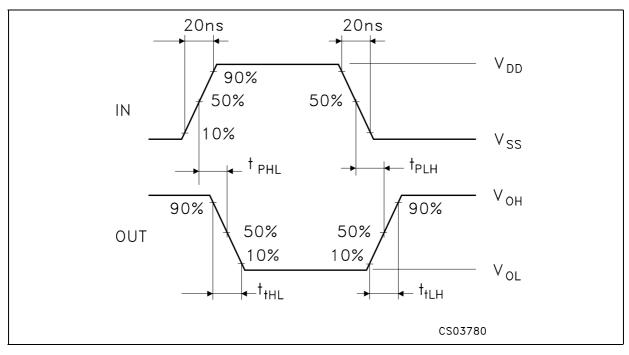
(*) Typical temperature coefficient for all V_{DD} value is 0.3%/°C.

TEST CIRCUIT



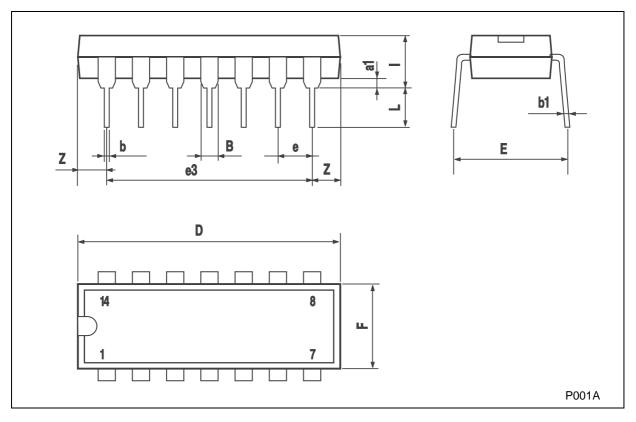
 C_L = 50pF or equivalent (includes jig and probe capacitance) R_L = 200KΩ R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



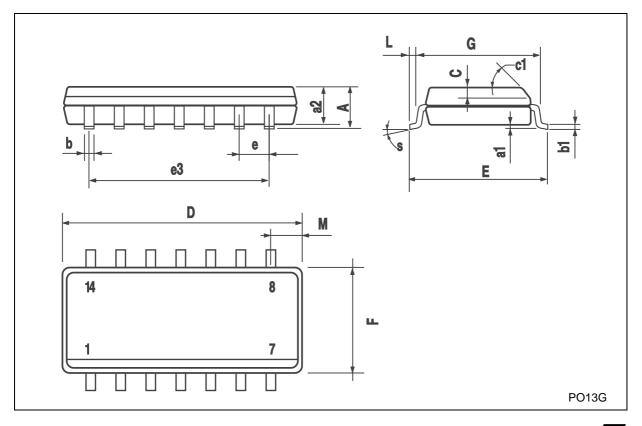
Plastic DIP-14 MECHANICAL DATA

DIM		mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
a1	0.51			0.020				
В	1.39		1.65	0.055		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
E		8.5			0.335			
е		2.54			0.100			
e3		15.24			0.600			
F			7.1			0.280		
I			5.1			0.201		
L		3.3			0.130			
Z	1.27		2.54	0.050		0.100		



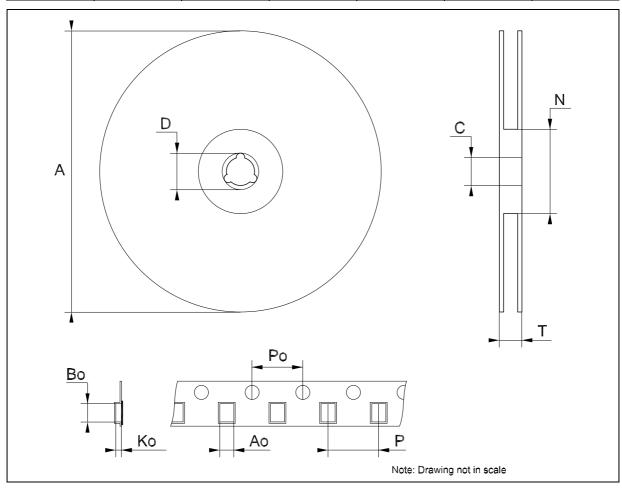
SO-14 MECHANICAL DATA

DIM		mm.		inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α			1.75			0.068	
a1	0.1		0.2	0.003		0.007	
a2			1.65			0.064	
b	0.35		0.46	0.013		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.019		
c1			45°	(typ.)			
D	8.55		8.75	0.336		0.344	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		7.62			0.300		
F	3.8		4.0	0.149		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.019		0.050	
М			0.68			0.026	
S		•	8° (r	max.)			



Tape & Reel SO-14 MECHANICAL DATA

DIM	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
N	60			2.362			
Т			22.4			0.882	
Ao	6.4		6.6	0.252		0.260	
Во	9		9.2	0.354		0.362	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	



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